



40V NPN LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > 40V
- Small Form Factor Thermally Efficient Package.
 Enables Higher Density End Products
- I_C = 2A High Continuous Collector Current
- I_{CM} = 3A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 320mV @ 1A
- Complementary PNP Type: DXTP22040DFG
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.03 grams (Approximate)

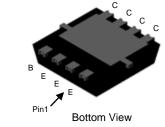
Applications

- DC to DC Conversion
- Supply Line Switching
- Low Drop Out Regulation
- LCD Backlighting

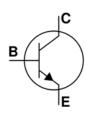
PowerDI3333-8 (SWP) (Type UX)



Top View



Equivalent Circuit



Device Symbol

Ordering Information

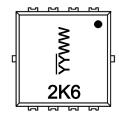
Part Number	Compliance	Marking	Reel Size (Inches)	Tape Width (mm)	Quantity per Reel
DXTN22040DFG-7	AEC-Q101	2K6	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K6 = Product Type Marking Code

\overline{\text{YY}}\text{WW} = Date Code Marking}

\overline{\text{YY}} = Last Two Digits of Year (ex: 21 = 2021)}

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	50	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	2	Α
Peak Pulse Collector Current	Ісм	3	Α
Continuous Base Current	I _B	100	mA
Peak Pulse Base Current	Івм	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Discipation	(Note 5)	D-	1.1	W
Power Dissipation	(Note 6)	PD	2.3	W
Thermal Decistores, Junction to Ambient	(Note 5)	0	113	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	55	°C/W
Thermal Resistance, Junction to Leads (Note	R _{θJL}	7.4	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

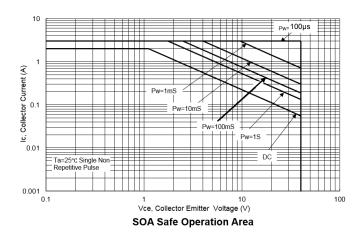
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Charge Device Model	CDM	1000	V	C5

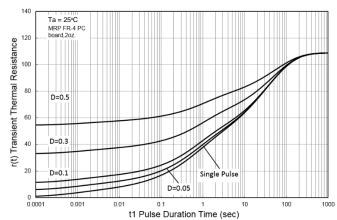
Notes:

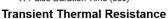
- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

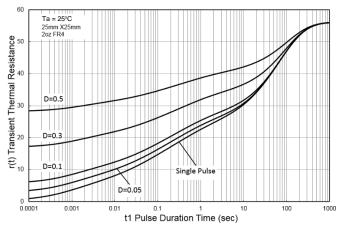


Thermal Characteristics and Derating Information

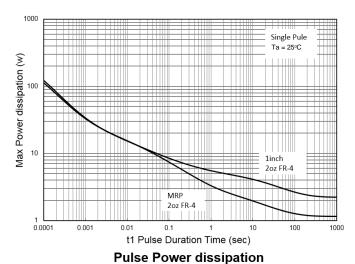


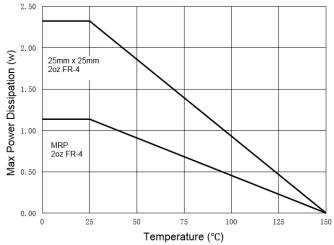






Transient Thermal Resistance





Derating Curve

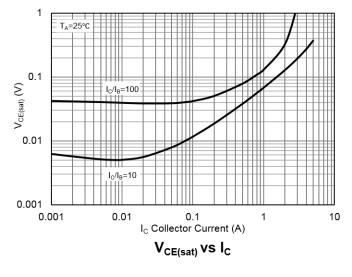


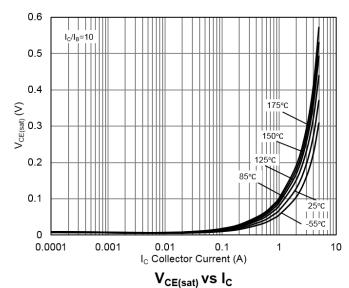
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

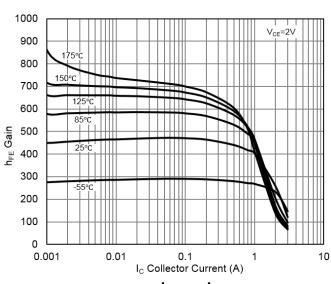
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	171	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BVceo	40	54	_	V	Ic = 10mA
Emitter-Base Breakdown Voltage	BVEBO	7	8.1	_	V	I _E = 100μA
Collector-Base Cut-Off Current	Ісво	_	1	50	nA	V _{CB} = 40V
			0.01	10	μA	$V_{CB} = 40V, T_A = +150^{\circ}C$
Emitter-Base Cut-Off Current	I _{EBO}	_	1	20	nA	V _{EB} = 6V
Collector-Emitter Cut-Off Current	ICES	_	1	50	nA	Vce = 40V, VBE = 0V
Static Forward Current Transfer Ratio (Note 9)	hFE	300 300 200 140	464 468 445 377	900 — —	_	Ic = 1mA, VcE = 2V Ic = 500mA, VcE = 2V Ic = 1A, VcE = 2V Ic = 2A, VcE = 2V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)		43 38 68 126 187	80 120 220 350 600	mV	IC = 100mA, IB = 1mA IC = 500mA, IB = 50mA IC = 1A, IB = 100mA IC = 2A, IB = 200mA IC = 3A, IB = 300mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}		0.9	1.1	V	Ic = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}		0.74	1	V	Ic = 1A, VcE = 5V
Input Capacitance	C _{ibo}	1	161	_	pF	$V_{EB} = 0.5V$, $f = 1MHz$
Output Capacitance	Cobo		11	_	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	fτ	_	198	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
	t _{delay}		7.9	_	ns	
Cuitakina Tima	trise	_	2.9	_	ns	Ic = 1A, Vcc = 10V,
Switching Time	tstorage	1	673	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$
	t _{fall}	-	26.8	_	ns	

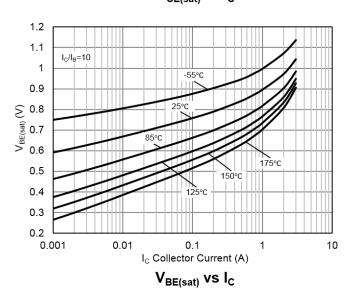
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

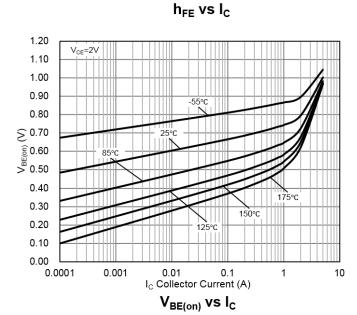


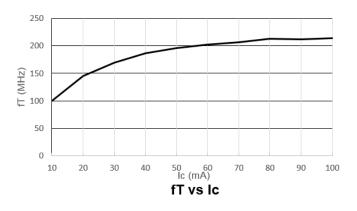










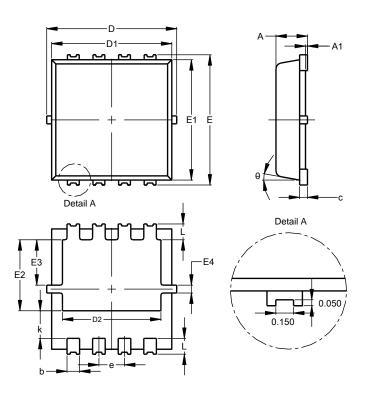




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

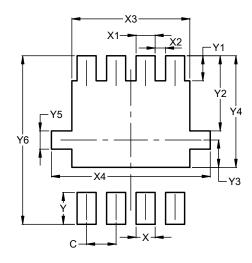


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	-	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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